Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	6	(("20020084254") or ("5,786,276") or ("6,433,381") or ("5,352,617") or ("6,383,866") or ("6,015,760")).PN.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/04/21 15:53
L2	1	("20040171261").PN.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/04/21 15:07
L3	3092	plasma same etch$3 near7 (silicon adj nitride sin sin>"sub.x" si<"sub.3" adj n<"sub.4") and semiconductor.clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 15:58
L4	2989	3 not (@ad>"20040225" @rlad>"20040225")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 15:58
L5	1247	4 and etch$3 near7 (silicon adj nitride sin sin>"sub.x" si<"sub.3" adj n<"sub.4") same selectiv$3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 16:00
L6	998	5 and etch$3 same (carbo$2fluoride carbo$2floride fluoride c adj$10 f fluoro near7 carbon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 16:09
L7	689	6 and etch$3 same (temperature heat$3 degree)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 16:10
L8	87	7 and etch$3 same (o2 "o?sub.2" oxygen) same (ar argon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 16:11
L9	87	8 and etch$3 same (o2 "o?sub.2" oxygen) same (ar argon)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/04/21 16:11